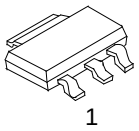
BCP69

PNP SILICON TRANSISTOR

PNP MEDIUM POWER TRANSISTOR



SOT-223

■ FEATURES

* High current (max. -1A)
* Low voltage (max. -20V).
* Complementary to UTC BCP68

■ APPLICATIONS

* General purpose switching and amplification
* Power applications such as audio output stages.

■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
BCP69L-xx-AA3-R	BCP69G-xx-AA3-R	SOT-223	B	C	E	Tape Reel

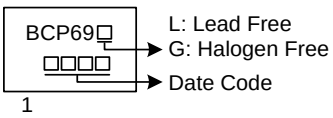
Note: Pin Assignment: B: Base C: Collector E: Emitter

BCP69G-xx-AA3-R

(1)Packing Type
(2)Package Type
(3)Rank
(4)Green Package

(1) R: Tape Reel
(2) AA3: SOT-223
(3) xx: refer to Classification of h_{FE3}
(4) G: Halogen Free and Lead Free, L: Lead Free

■ MARKING



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■ ABSOLUTE MAXIMUM RATING (T_A=25°C , unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage (Open Emitter)	V_{CBO}	-32	V
Collector-Emitter Voltage (Open Base)	V_{CEO}	-20	V
Emitter-Base Voltage (Open Collector)	V_{EBO}	-5	V
Collector Current (DC)	I_C	-1	A
Peak Collector Current	I_{CM}	-2	A
Peak Base Current	I_{BM}	-200	mA
Total Power Dissipation, T_A ≤25°C	P_D	1.35	W
Junction Temperature	T_J	+150	°C
Operating Temperature	T_{OPR}	-45 ~ +150	°C
Storage Temperature	T_{STG}	-65 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	91	K/W

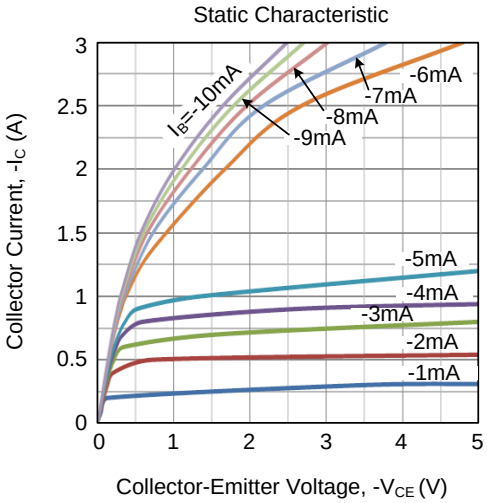
■ ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified.)

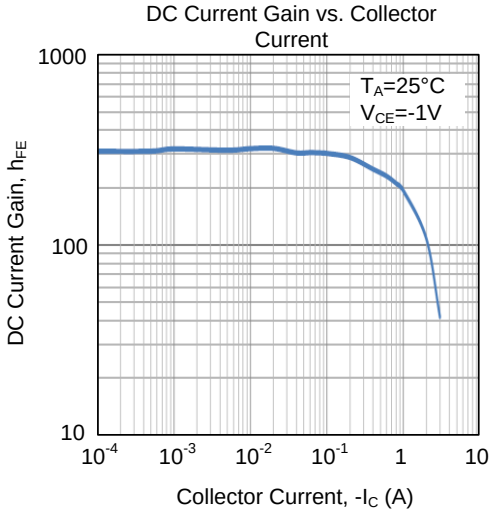
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	I_C=-1A, I_B=-100mA			-500	mV
Base-Emitter Voltage	V_{BE}	I_C=-5mA, V_{CE}=-10V		-620		mV
		I_C=-1A, V_{CE}=-1V			-1	V
Collector Cut-off Current	I_{CBO}	I_E=0, V_{CB}=-25V			-100	nA
		I_E=0, V_{CB}=-25V,T_J=150°C			-10	μA
Emitter Cut-off Current	I_{EBO}	I_C=0, V_{EB}=-5V			-100	nA
DC Current Gain	h_{FE}	I_C=-500mA, V_{CE}=-1V	85		375	
	h_{FE1}	I_C=-5mA, V_{CE}=-10V	50			
	h_{FE2}	I_C=-1A, V_{CE}=-1V	60			
	h_{FE3}	I_C=-500mA, V_{CE}=-1V	100		375	
Collector Capacitance	C_C	I_E=i_e=0, V_{CB}=-5V, f=1MHz		48		pF
Transition Frequency	f_T	I_C=-10mA, V_{CE}=-5V, f=100MHz	40			MHz
DC current gain ratio of the complementary pairs	$\frac{h_{FE1}}{h_{FE2}}$	|I_C|=0.5A, |V_{CE}|=1V			1.6	

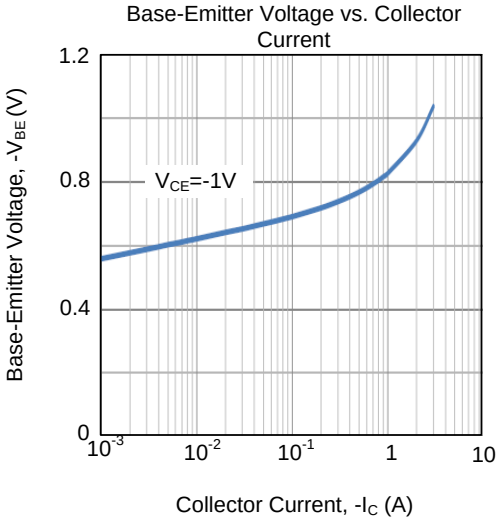
■ CLASSIFICATION OF h_{FE3}

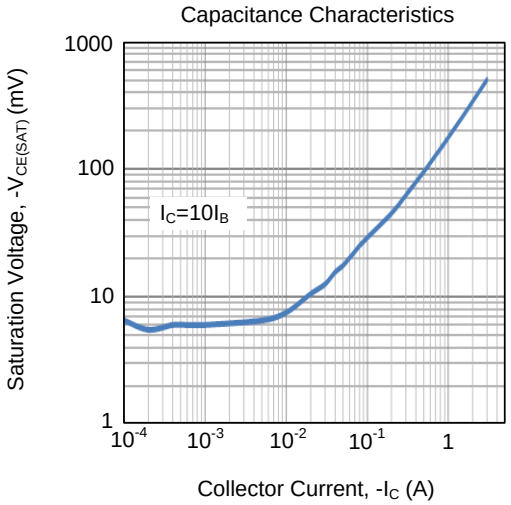
RANK	16	25
RANGE	100~250	160~375

■ TYPICAL CHARACTERISTICS









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